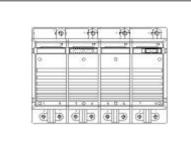
# SKiiP 132GDL120-4DU



### SKiiP<sup>®</sup> 2

7-pack - integrated intelligent Power System

Power section - 3 phase bridge

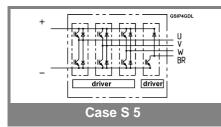
SKiiP 132GDL120-4DU

#### **Power section features**

- SKiiP technology inside
- CAL diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiiP<sup>®</sup> 2 System)
- IEC 60068-1 (climate) 40/125/56
- UL recognized file no. E63532
- 1) with assembly of suitable MKP capacitor per terminal

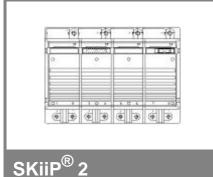
Absolute	Maximum Ratings	$_{\rm s}$ = 25 °C unless otherwise specified				
Symbol	Conditions	Values	Units			
IGBT						
V <sub>CES</sub>		1200	V			
V <sub>CES</sub> V <sub>CC</sub> <sup>1)</sup>	Operating DC link voltage	900	V			
V <sub>GES</sub>		± 20	V			
I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	150 (112,5)	А			
Inverse diode						
I <sub>F</sub> = - I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	150 (112,5)	А			
I <sub>FSM</sub>	$T_{j} = 150 \text{ °C}, t_{p} = 10 \text{ ms}; \text{ sin.}$	1440	А			
I²t (Diode)	Diode, T <sub>j</sub> = 150 °C, 10 ms	10	kA²s			
T <sub>j</sub> , (T <sub>stg</sub> )		- 40 (- 25) + 15 0 (125)	°C			
V <sub>isol</sub>	AC, 1 min. (mainterminals to heat sink)	3000	V			

Characteristics				$T_s = 25 \ ^{\circ}C$ unless otherwise specified				
Symbol	Conditions			min.	typ.	max.	Units	
IGBT								
V <sub>CEsat</sub>	I <sub>C</sub> = 125 A,		25) °C			2,6 (3,1)		V
V <sub>CEO</sub>	T <sub>j</sub> = 25 (12					• •	1,5 (1,6)	V
r <sub>CE</sub>	$T_{j} = 25 (125)$					10,5 (14)	12,6 (16,1)	mΩ
I <sub>CES</sub>	V <sub>GE</sub> = 0 V,	$V_{CE} = V_{CE}$	ES'			(10)	0,4	mA
	T <sub>j</sub> = 25 (12	5) °C						
E <sub>on</sub> + E <sub>off</sub>	I <sub>C</sub> = 125 A,	V <sub>CC</sub> = 60	0 V				38	mJ
	T <sub>j</sub> = 125 °C	s, V <sub>CC</sub> = 90	V 00				66	mJ
R <sub>CC' + EE'</sub>	terminal ch	ip, T <sub>i</sub> = 12	5 °C			0,5		mΩ
L <sub>CE</sub>	top, bottom	, I				15		nH
C <sub>CHC</sub>	per phase,	AC-side				1,4		nF
Inverse o	diode				•			
V <sub>F</sub> = V <sub>EC</sub>	I <sub>F</sub> = 150 A,	T <sub>i</sub> = 25 (1	25) °C			2,1 (1,9)	2,6	V
V <sub>TO</sub>	T <sub>i</sub> = 25 (125					1,3 (1)	1,4 (1,1)	V
r <sub>T</sub>	$T_{j} = 25 (125)$					5 (6)	6,8 (7,8)	mΩ
Err	I <sub>C</sub> = 125 A,	$V_{\rm CC} = 60$	0 V				6	mJ
	T <sub>j</sub> = 125 °C	s, V <sub>CC</sub> = 90	V 00				8	mJ
Mechani	cal data							
M <sub>dc</sub>	DC termina	als, SI Unit	s		6		8	Nm
$M_{ac}$	AC termina				13		15	Nm
w	SKiiP <sup>®</sup> 2 System w/o heat sink				3,5		kg	
w	heat sink					8,5		kg
Thermal	character	ristics (	P16 hea	t sink; 2 <sup>.</sup>	75 m <sup>3</sup> /h);	" <sub>_</sub> " refe	rence to	
temperat	ture sense	or				I	_	
R <sub>th(j-s)I</sub>	per IGBT						0,18	K/W
R <sub>th(j-s)D</sub>	per diode						0,375	K/W
R <sub>th(s-a)</sub>	per module						0,036	K/W
Z <sub>th</sub>	R <sub>i</sub> (mK/W) (max. values)			tau <sub>i</sub> (s)				
	1	2	3	4	1	2	3	4
Z <sub>th(j-r)I</sub>	20	139	22	0	1	0,13	0,001	1
Z <sub>th(j-r)D</sub>	41	289	45	0	1	0,13	0,001	1
Z <sub>th(r-a)</sub>	1,7	24	7,6	2,6	494	165	20	0,03



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# SKiiP 132GDL120-4DU



### 7-pack - integrated intelligent Power System

7-pack integrated gate driver - 3 phase bridge SKiiP 132GDL120-4DU

#### Gate driver features

- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- Interlock of top/bottom switch
- Isolation by transformer
- IEC 60068-1 (climate) 40/85/56

Absolute	Maximum Ratings	a = 25 °C unless otherwise specified		
Symbol	Conditions	Values	Units	
V <sub>S1</sub> V <sub>S2</sub>	stabilized 15 V power supply unstabilized 24 V power supply	18 30	V V	
V <sub>iH</sub>	input signal voltage (high)	15 + 0,3	V	
dv/dt	secondary to primary side	75	kV/μs	
V <sub>isolIO</sub>	input / output (AC, r.m.s., 2s )	3000	Vac	
V <sub>isol12</sub>	output 1 / output 2 (AC, r.m.s., 2s )	1500	Vac	
f <sub>sw</sub>	switching frequency	20	kHz	
f <sub>out</sub>	output frequency for I=I <sub>C</sub> ;sin.	1	kHz	
$T_{op} (T_{stg})$	operating / storage temperature	- 40 + 85	°C	

Characteristics (T <sub>a</sub> = 2					= 25 °C)
Symbol	Conditions	min.	typ.	max.	Units
V <sub>S1</sub>	supply voltage stabilized	14,4	15	15,6	V
V <sub>S2</sub>	supply voltage non stabilized	20	24	30	V
I <sub>S1</sub>	V <sub>S1</sub> = 15 V	410+280	410+280*f/f <sub>max</sub> +3,6*(I <sub>AC</sub> /A)		
I <sub>S2</sub>	V <sub>S2</sub> = 24 V	300+200	300+200*f/f <sub>max</sub> +2,6*(I <sub>AC</sub> /A)		
V <sub>iT+</sub>	input threshold voltage (High)			12,3	V
V <sub>iT-</sub>	input threshold voltage (Low)	4,6			V
R <sub>IN</sub>	input resistance		10		kΩ
t <sub>d(on)IO</sub>	input-output turn-on propagation time			1,5	μs
t <sub>d(off)IO</sub>	input-output turn-off propagation time			1,4	μs
t <sub>pERRRESET</sub>	error memory reset time	9			μs
t <sub>TD</sub>	top / bottom switch : interlock time		2,3		μs
I <sub>analogOUT</sub>	8 V corresponds to max. current of 15 V supply voltage		150		A
I <sub>Vs1outmax</sub>	(available when supplied with 24 V)			50	mA
I <sub>A0max</sub>	output current at pin 13/20/22/24/26			5	mA
V <sub>0I</sub>	logic low output voltage			0,6	V
V <sub>0H</sub>	logic high output voltage			30	V
I <sub>TRIPSC</sub>	over current trip level (I <sub>analog OUT</sub> = 10 V)		188		A
I <sub>TRIPLG</sub>	ground fault protection		43		А
T <sub>tp</sub>	over temperature protection	110		120	°C
UDCTRIP	trip level of U <sub>DC</sub> -protection	900			V
	( U <sub>analog OUT</sub> = 9 V); (option)				

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